

# HER151 - HER158

## 1.5 AMPS. High Efficient Rectifiers

### DO-15

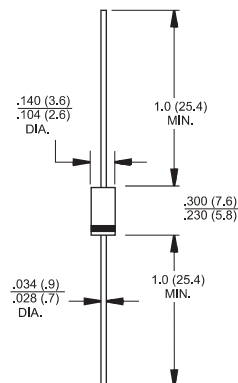


## Features

- ✧ High efficiency, Low VF
- ✧ High current capability
- ✧ High reliability
- ✧ High surge current capability
- ✧ For use in low voltage, high frequency inverter, free wheeling, and polarity protection application.

## Mechanical Data

- ✧ Case: Molded plastic DO-15
- ✧ Epoxy: UL 94V0 rate flame retardant
- ✧ Lead: Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: Color band denotes cathode
- ✧ High temperature soldering guaranteed: 260°C/10 seconds/.375", (9.5mm) lead lengths at 5 lbs., (2.3kg) tension
- ✧ Mounting position: Any
- ✧ Weight: 0.40 gram



Dimensions in inches and (millimeters)

## Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.  
Single phase, half wave, 60 Hz, resistive or inductive load.  
For capacitive load, derate current by 20%

Type Number	Symbol	HER 151	HER 152	HER 153	HER 154	HER 155	HER 156	HER 157	HER 158	Units	
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	200	300	400	600	800	1000	V	
Maximum RMS Voltage	$V_{RMS}$	35	70	140	210	280	420	560	700	V	
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	300	400	600	800	1000	V	
Maximum Average Forward Rectified Current .375 (9.5mm) Lead Length @ $T_A = 55^\circ\text{C}$	$I_{(AV)}$	1.5								A	
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method )	$I_{FSM}$	50								A	
Maximum Instantaneous Forward Voltage @ 1.5A	$V_F$	1.0			1.3		1.7			V	
Maximum DC Reverse Current @ $T_A = 25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_A = 125^\circ\text{C}$	$I_R$	5.0 150								uA uA	
Maximum Reverse Recovery Time ( Note 1 )	$T_{rr}$	50					75				nS
Typical Junction Capacitance ( Note 2 )	$C_j$	50					35				pF
Typical thermal resistance	$R_{\theta JA}$	60								°C/W	
Operating Temperature Range	$T_J$	-65 to +150								°C	
Storage Temperature Range	$T_{STG}$	-65 to +150								°C	

- Notes
1. Reverse Recovery Test Conditions:  $I_F = 0.5\text{A}$ ,  $I_R = 1.0\text{A}$ ,  $I_{RR} = 0.25\text{A}$
  2. Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.
  3. Mount on Cu-Pad Size 10mm x 10mm on PCB.

## RATINGS AND CHARACTERISTIC CURVES (HER151 THRU HER158)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

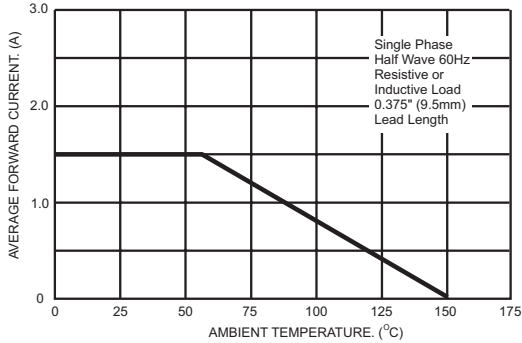


FIG.2- TYPICAL REVERSE CHARACTERISTICS

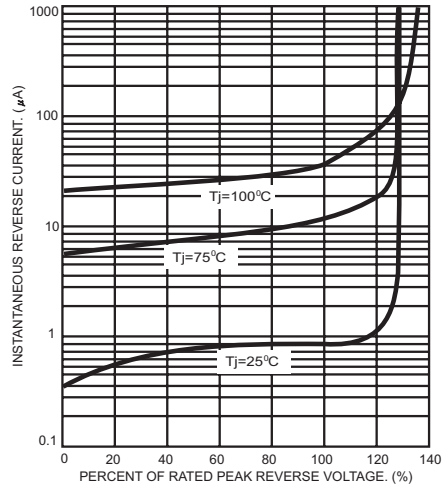


FIG.3- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

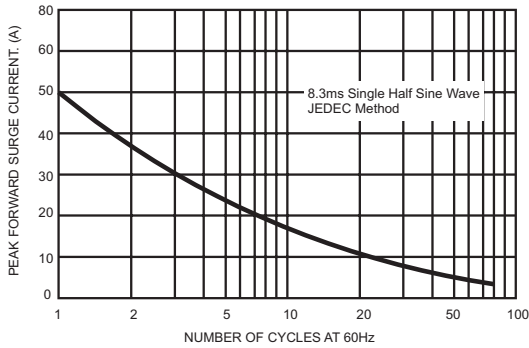


FIG.5- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

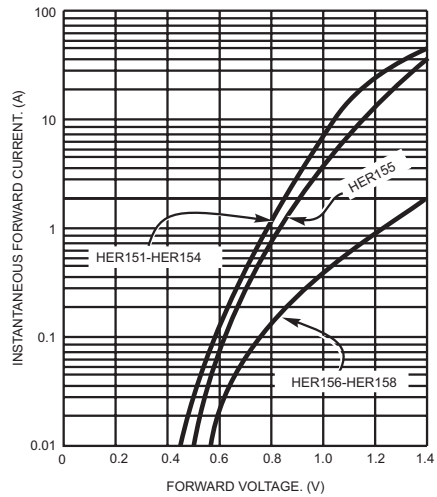


FIG.4- TYPICAL JUNCTION CAPACITANCE

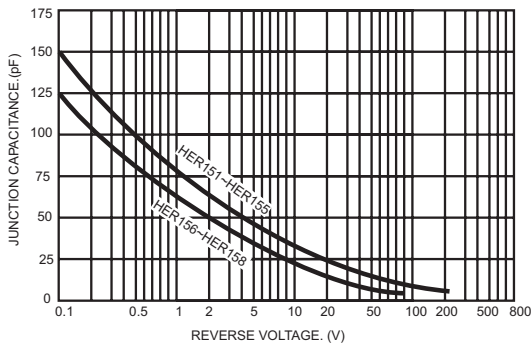
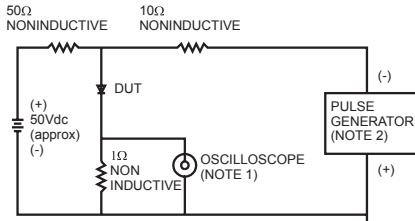


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES: 1. Rise Time=7ns max. Input Impedance=1 megohm 22pf  
2. Rise Time=10ns max. Source Impedance=50 ohms

